TECHSEM

Y24ZPA
RECTIFIER DIODE

Features
- Low forward voltage drop
- High reverse voltage
- Hermetic metal cases with ceramic insulators

Typical Applications
- All purpose high power rectifier diodes
- High power resistance welding equipment
- Non-controllable and half-controllable rectifiers
- Controlled rectifiers

$I_{F(AV)}$	**1080 A**
V_{RRM}	**200~600 V**
I_{FSM}	**8 kA**
I^2t	**320 10^3A^2S**

SYMBOL	CHARACTERISTIC	TEST CONDITIONS		T_j(°C)	VALUE			UNIT
					Min	Type	Max	
$I_{F(AV)}$	Mean forward current	180° half sine wave 50Hz Double side cooled,	T_C=55°C	190			1080	A
			T_C=85°C				920	
V_{RRM}	Repetitive peak reverse voltage	V_{RRM} tp=10ms V_{RSM}= V_{RRM}+100V		190	200		600	V
I_{RRM}	Repetitive peak current	V_{RM}= V_{RRM}		190			16	mA
I_{FSM}	Surge forward current	10ms half sine wave V_R=0.6V_{RRM}		190			8	kA
I^2t	I^2T for fusing coordination						320	A^2s*10^3
V_{FO}	Threshold voltage			190			0.71	V
r_F	Forward slop resistance						0.32	mΩ
V_{FM}	Peak on-state voltage	I_{FM}=1000A, F=5kN		190			1.10	V
Q_{rr}	Recovery charge	I_{FM}=1000A,tp=2000μs, di/dt=-20A/μs, V_R=50V		190		1200		μC
$R_{th(j-c)}$	Thermal resistance Junction to case	At 180^0 sine, double side cooled Clamping force 5.0kN					0.08	°C /W
$R_{th(c-h)}$	Thermal resistance case to heat sink						0.02	
F_m	Mounting force				3.3		5.5	kN
T_{stg}	Stored temperature				-40		190	°C
W_t	Weight					60		g
Outline	ZT19aT							

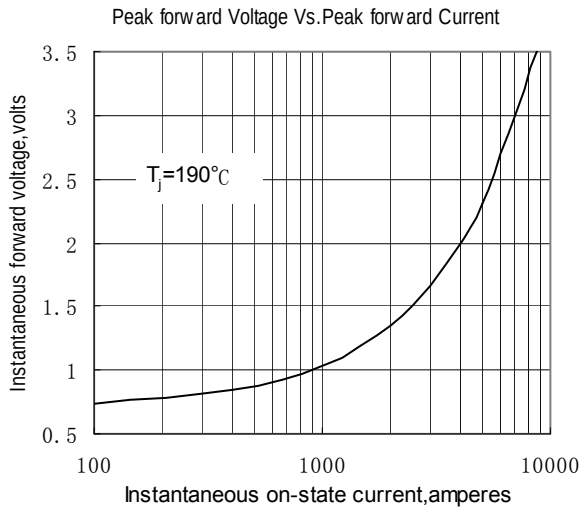

Fig.1

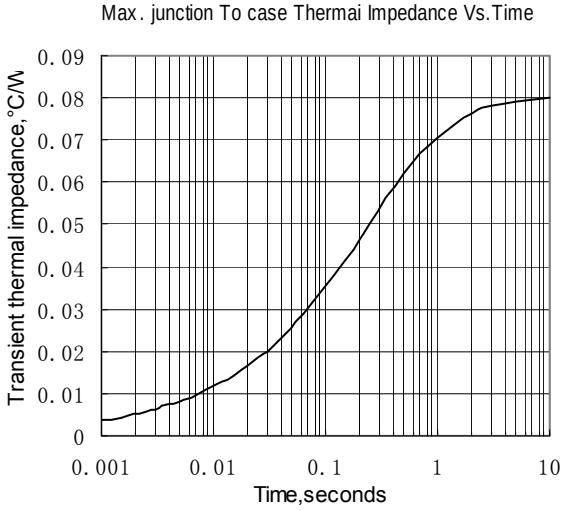

Fig.2

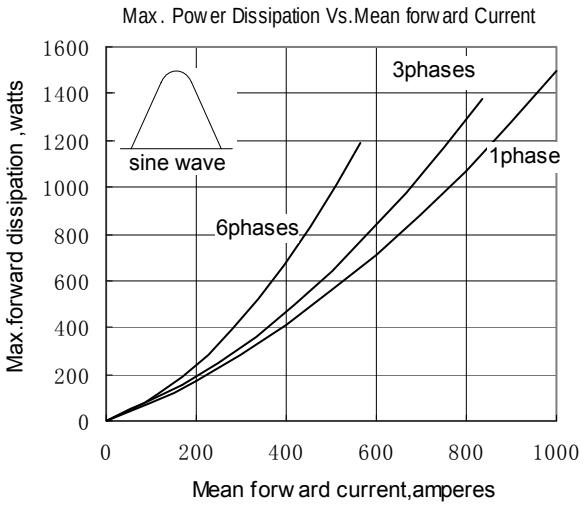

Fig.3

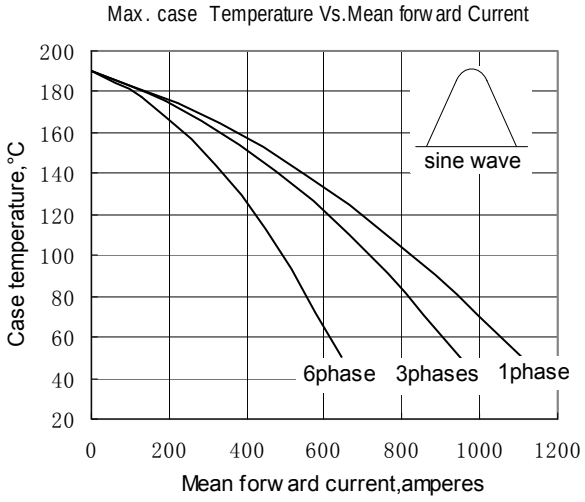

Fig.4

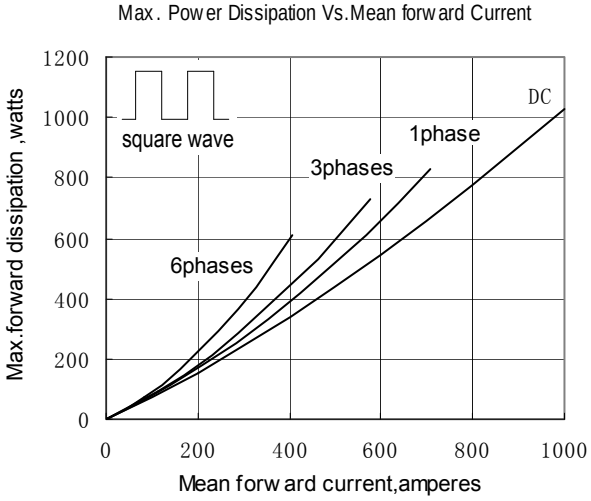

Fig.5

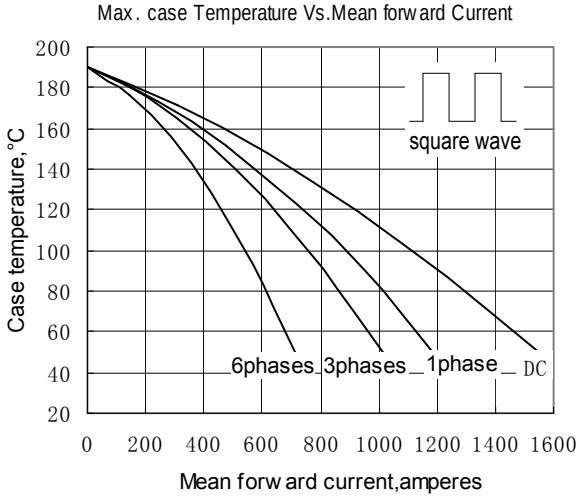

Fig.6

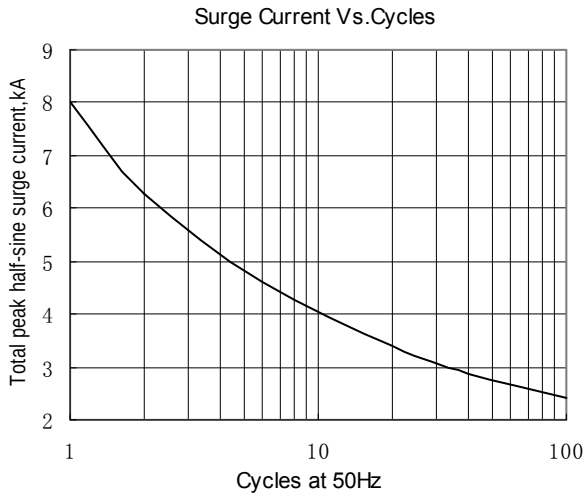

Fig.7

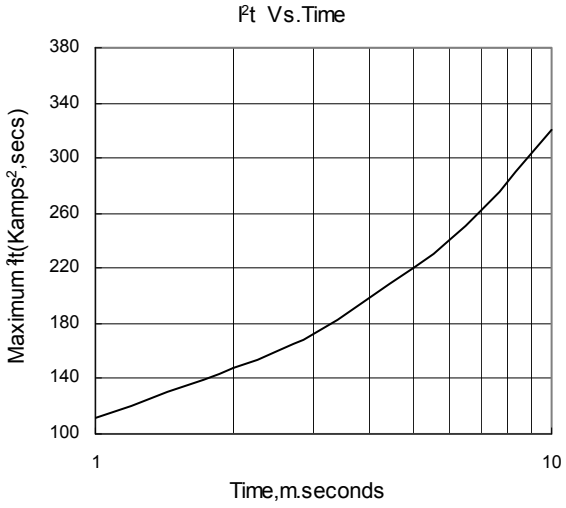

Fig.8

Outline: